

STC12IE90HV

Emitter Switched Bipolar Transistor ESBT® 900 V - 12 A - 0.083 Ω

Preliminary Data

General features

V _{CS(ON)}	Ic	R _{CS(ON)}
1V	12A	0.083 Ω

- High voltage / high current Cascode configuration
- Low equivalent on resistance
- Very fast-switch up to 150 kHz
- Squared RBSOA up to 900V
- Very low C_{iss} driven by $R_G = 47\Omega$
- Very low turn-off cross over time

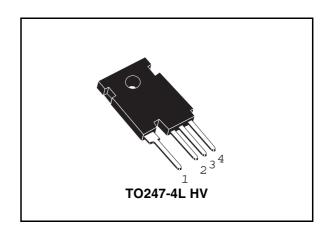
Applications

■ Aux Smps For Three Phase Mains

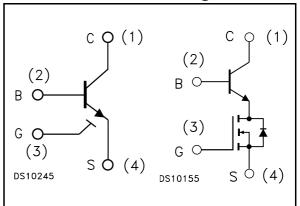
Description

The STC12IE90HV is manufactured in Monolithic ESBT Technology, aimed to provide best performances in high frequency / high voltage applications.

It is designed for use in Gate Driven based topologies.



Internal schematic diagrams



Order codes

Part Number	Marking	Package	Packaging
STC12IE90HV	C12IE90HV	TO247-4L HV	Tube

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STC12IE90HV Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CS(SS)}	Collector-source voltage (V _{BS} = V _{GS} = 0 V)	900	V
V _{BS(OS)}	Base-source voltage (I _C = 0, V _{GS} = 0 V)	30	V
V _{SB(OS)}	Source-base voltage (I _C = 0, V _{GS} = 0 V)	17	V
V _{GS}	Gate-source voltage	土 17	V
I _C	Collector current	12	Α
I _{CM}	Collector peak current (t _P < 5ms)	36	Α
Ι _Β	Base current	6	Α
I _{BM}	Base peak current (t _P < 5ms)	10	Α
P _{tot}	Total dissipation at T _c = 25°C	208	W
T _{stg}	Storage temperature	-40 to 150	°C
T _J	Max. operating junction temperature	150	°C

Table 2. Thermal data

Symbo	Parameter		Value	Unit
R _{thj-cas}	Thermal resistance junction-case	max	0.6	°C/W

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Electrical characteristics STC12IE90HV

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 3. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CS(SS)}	Collector-source current (V _{BS} = V _{GS} = 0)	V _{CE} = 900V			100	μΑ
I _{BS(OS)}	Base-source current (I _C = 0, V _{GS} = 0)	V _{BS(OS)} = 30V			10	μΑ
I _{SB(OS)}	Source-base current (I _C = 0, V _{GS} = 0)	V _{SB(OS)} = 17V			100	μА
I _{GS(OS)}	Gate-source leakage	V _{GS} = ± 17V			100	nA
V _{CS(ON)}	Collector-source ON voltage	$V_{GS} = 10V$ $I_C = 12A$ $I_B = 2.4A$ $V_{GS} = 10V$ $I_C = 6A$ $I_B = 0.6A$		1 0.6		V V
h _{FE}	DC current gain	$V_{GS} = 10V I_C = 12A V_{CS} = 1V$ $V_{GS} = 10V I_C = 6A V_{CS} = 1V$		5 15		
V _{BS(ON)}	Base Source ON voltage	$V_{GS} = 10V I_C = 12A I_B = 2.4A$ $V_{GS} = 10V I_C = 6A I_B = 0.6A$		1.5 1.2		V V
V _{GS(th)}	Gate threshold voltage	$V_{BS} = V_{GS}$ $I_B = 250 \mu A$	2	3	4	V
C _{iss}	Input capacitance	$V_{CS} = 25V$ f = 1MHz $V_{GS} = 0V$		520		pF
Q _{GS(tot)}	Gate-source Charge	V _{CS} =25V V _{GS} =10V V _{CB} =0V I _C =4A		21.3		nC
t _s	INDUCTIVE LOAD Storage time Fall time	$\begin{aligned} &V_{GS} = 10V & R_G = 47\Omega \\ &V_{Clamp} = 720V & t_p = 4\mu s \\ &I_C = 6A & I_B = 1.2A \end{aligned}$		610 10		ns ns
t _s	INDUCTIVE LOAD Storage time Fall time	$\begin{aligned} &V_{GS}=&10V & R_{G}=&47\Omega \\ &V_{Clamp}=&720V & t_{p}=&4\mu s \\ &I_{C}=&6A & I_{B}=&0.6A \end{aligned}$		360 10		ns ns
V _{CSW}	Maximum collector- source voltage switched without snubber	$R_G = 47\Omega$ $h_{FE} = 5$ $I_C = 12A$	900			٧

Table 3. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{CS(dyn)}	Collector-source dynamic voltage (500ns)	$\begin{aligned} &V_{CC} = &V_{Clamp} = &400 V \\ &V_{GS} = &10 V &I_{C} = &6 A \\ &I_{B} = &1.2 A &t_{peak} = &500 ns \\ &R_{G} = &47 \Omega &I_{Bpeak} = &6 A \left(I_{C} \right) \end{aligned}$		3.37		V
V _{CS(dyn)}	Collector-source dynamic voltage (1µs)	$\begin{aligned} &V_{CC} = &V_{Clamp} = &400V \\ &V_{GS} = &10V & I_{C} = &6A \\ &I_{B} = &1.2A & t_{peak} = &500ns \\ &R_{G} = &47\Omega & I_{Bpeak} = &6A \left(I_{C}\right) \end{aligned}$		1.75		V

2.1 Electrical characteristics (curves)

Figure 1. DC current gain

Figure 2. Collector-source On voltage

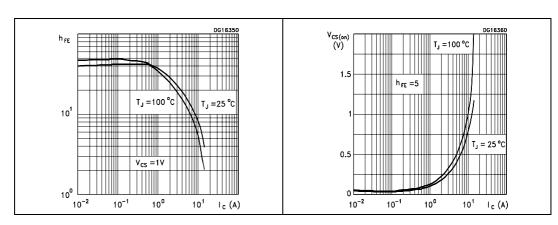
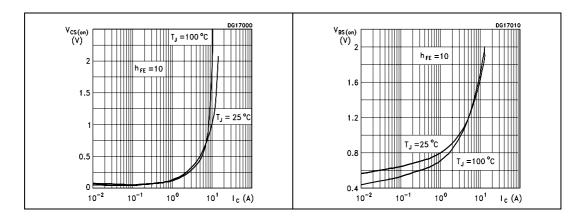


Figure 3. Collector-source On voltage Figure 4. Base-source On voltage



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Figure 5. Reverse biased SOA

Figure 6. Dynamic collector-emitter voltage

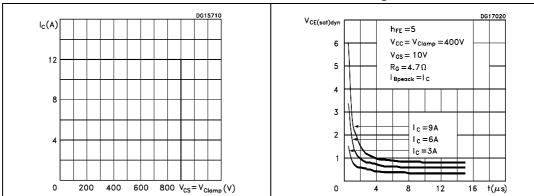
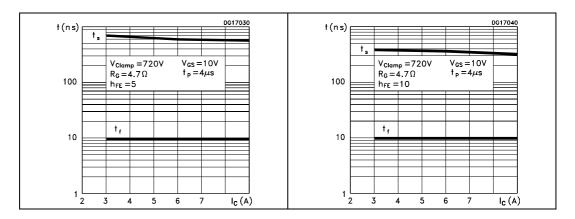


Figure 7. Inductive load switching time Figure 8. Inductive load switching time



2.2 Test circuits

Figure 9. Static V_{CS(ON)} test circuits

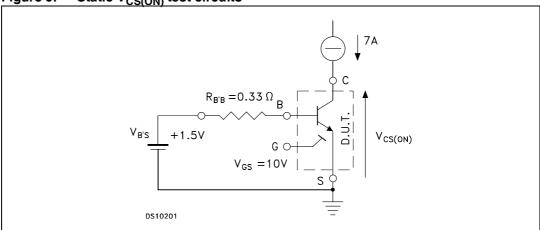
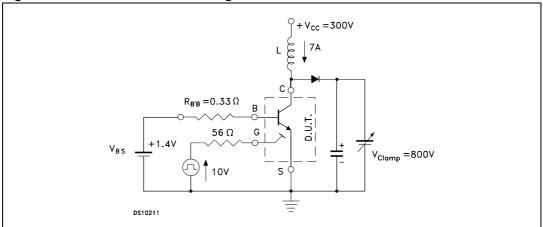


Figure 10. Inductive load switching and RBSOA test circuit

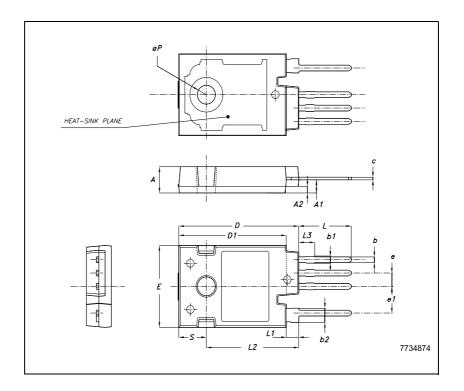


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO247-4L HV MECHANICAL DATA

DIM.		mm.	
DIWI.	MIN.	TYP	MAX.
Α	4.85		5.15
A1	2.20	2.50	2.60
A2		1.27	
b	0.95	1.10	1.30
b2	2.50		2.90
С	0.40		0.80
D	23.85	24	24.15
D1		21.50	
E	15.45	15.60	15.75
е	2.54		
e1	5.08		
L	10.20		10.80
L1	2.20	2.50	2.80
L2		18.50	
L3		3	
øΡ	3.55		3.65
S		5.50	



Revision history STC12IE90HV

4 Revision history

Table 4. Revision history

Date	Revision	Changes
16-Jan-2007	1	Initial release.

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